

S4810, S6289

Operation at low voltage from 2.2 V

The S4810 and S6289 are digital output photo ICs consisting of a photodiode, schmitt trigger circuit and output transistor, all integrated on a single chip and molded into a visible-cut, subminiature plastic package.

Features

- Low-voltage operation: 2.2 to 7 V
- Subminiature plastic package with lens
- Low current consumption
- Open collector output
- S4810: "H" level output at light input
S6289: "L" level output at light input

Applications

- Cameras
- Tape start/end mark sensor for VTRs, cassette tape recorders, etc.
- Optical switches
- Encoders

Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Supply voltage	Vcc	-0.5 to +7	V
Output voltage	Vo	-0.5 to +7	V
Output current	Io	8	mA
Power dissipation	P	150	mW
Operating temperature	Topr	-25 to +85	°C
Storage temperature	Tstg	-40 to +100	°C
Soldering	-	260 °C, 3 s, at least 2.5 mm away from package surface	-

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Electrical and optical characteristics (Ta=25 °C, Vcc=5 V, light source: λp=890 nm LED, unless otherwise noted)

Parameter	Symbol	Condition	S4810			S6289			Unit
			Min.	Typ.	Max.	Min.	Typ.	Max.	
Supply voltage	Vcc		2.2	-	7.0	2.2	-	7.0	V
Low level output voltage	VOL	IOL=4 mA*1	-	-	0.4	-	-	0.4	V
High level output current	IOH	VO=5 V*2	-	-	10	-	-	10	μA
Current consumption	ICC		-	1.3	3	-	1.3	3	mA
L→H Threshold illuminance	ELH	RL=1.2 kΩ	-	-	1.5	-	-	-	μW/mm ²
H→L Threshold illuminance	EHL	RL=1.2 kΩ	-	-	-	-	-	1.5	μW/mm ²
Hysteresis	-	*3	-	0.9	-	-	0.85	-	-
L→H Propagation delay time	tPLH	2 μW/mm ² RL=1.2 kΩ	-	-	10	-	-	15	μs
H→L Propagation delay time	tPHL		-	-	15	-	-	10	μs
Rise time	tr		-	0.07	-	-	0.07	-	μs
Fall time	tf		-	0.03	-	-	0.03	-	μs
Peak sensitivity wavelength	λp		-	850	-	-	850	-	nm

*1: S4810: E (illuminance) =0 μW/mm², S6289: E=2 μW/mm²

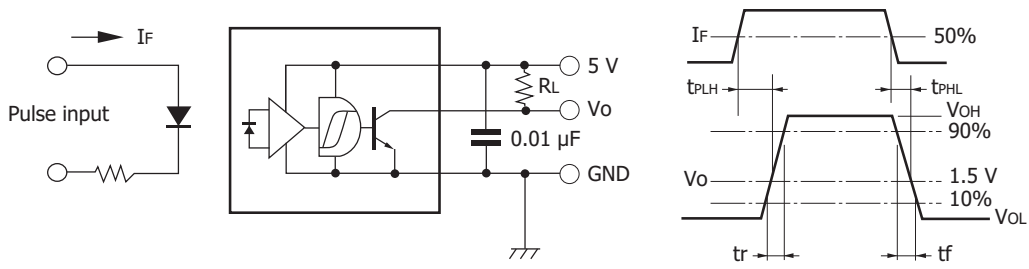
*2: S4810: E=2 μW/mm², S6289: E=0 μW/mm²

*3: S4810: EHL/ELH, S6289: ELH/EHL

Note: Connect a 0.01 μF capacitor or larger between Vcc and GND.

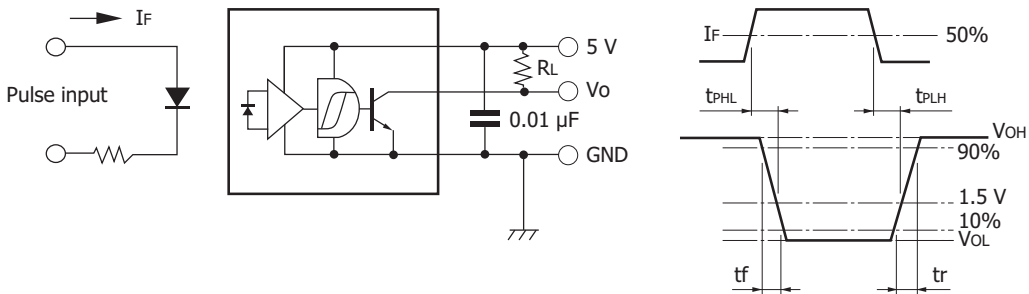
Response time measurement circuit

S4810



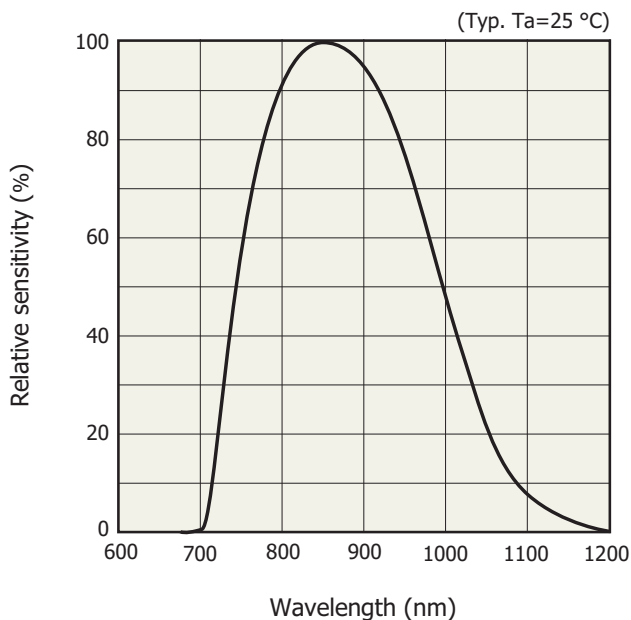
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S6289



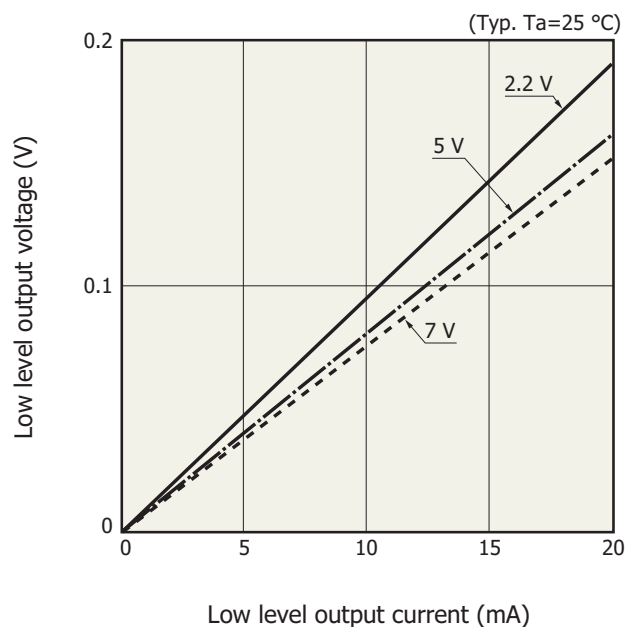
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Spectral response



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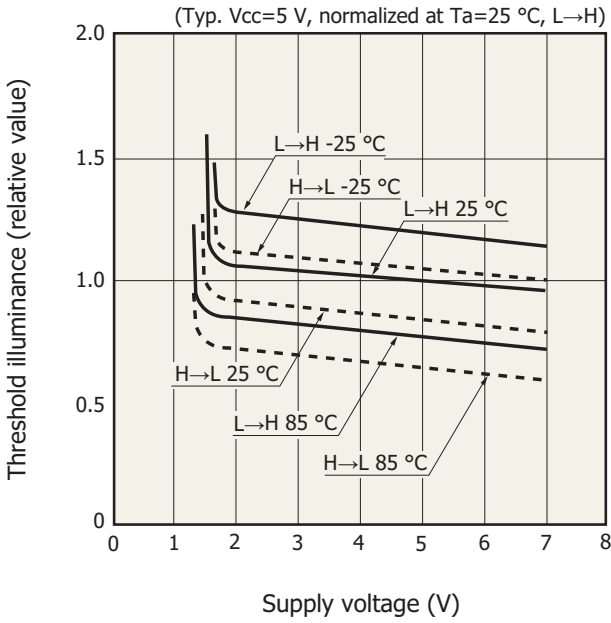
Low level output voltage vs. low level output current



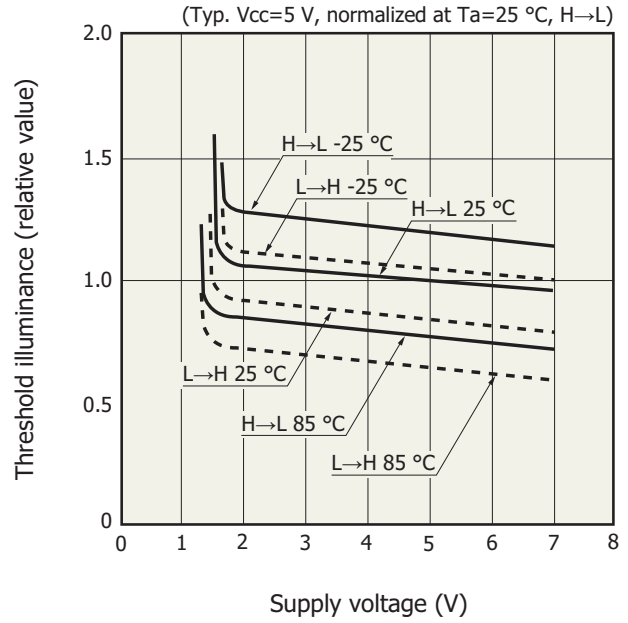
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Threshold illuminance vs. supply voltage

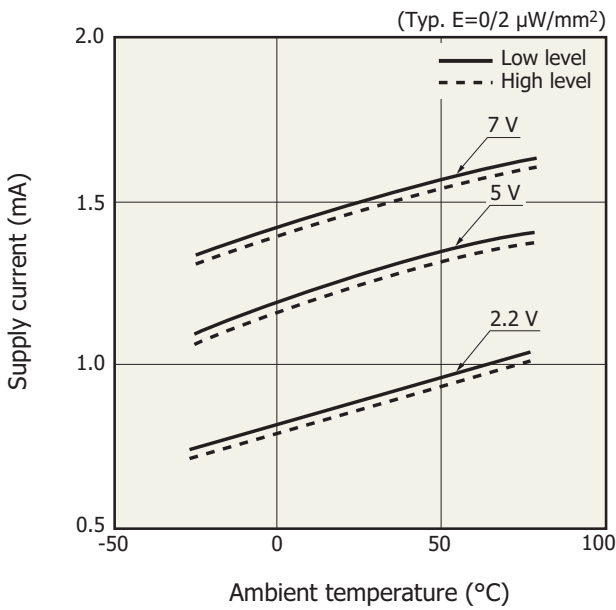
S4810



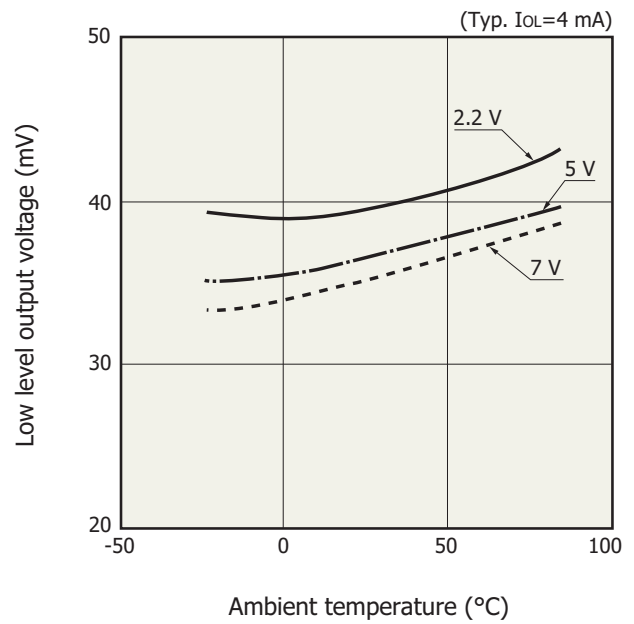
S6289



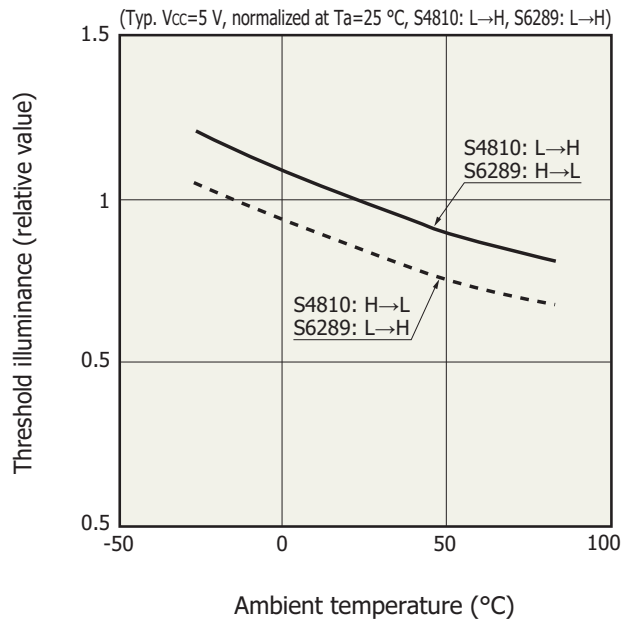
Supply current vs. ambient temperature



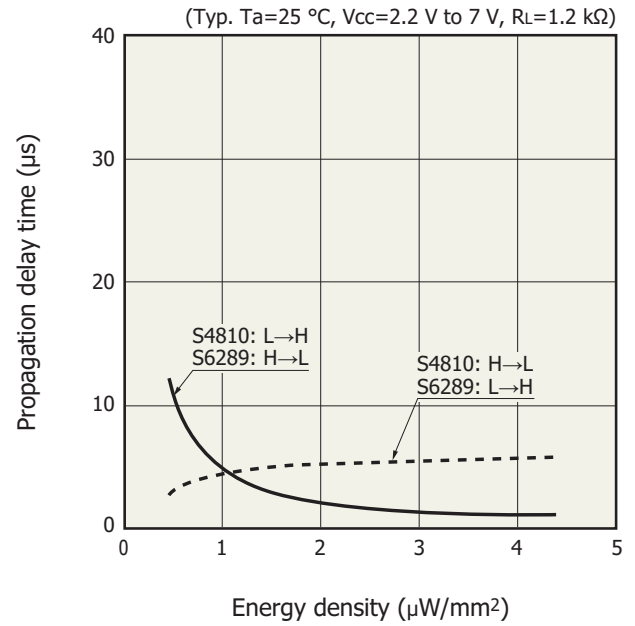
Low level output voltage vs. ambient temperature



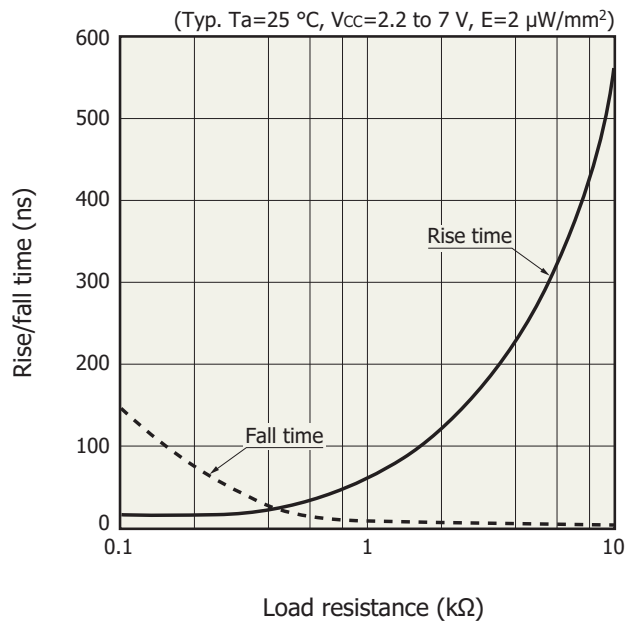
Threshold illuminance vs. ambient temperature



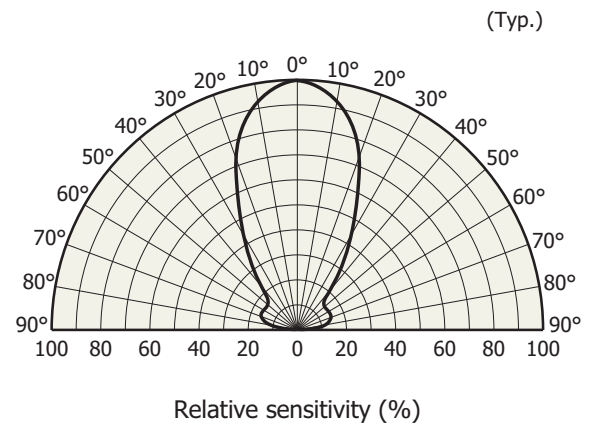
Propagation delay time vs. input light strength



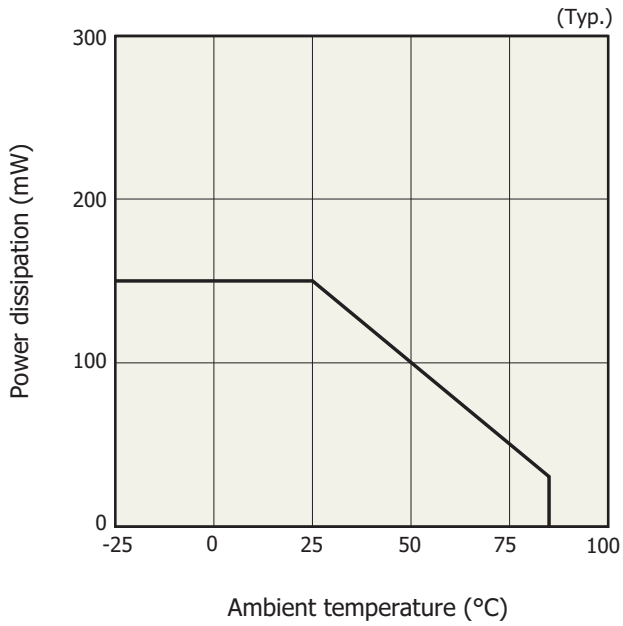
Rise/fall time vs. load resistance



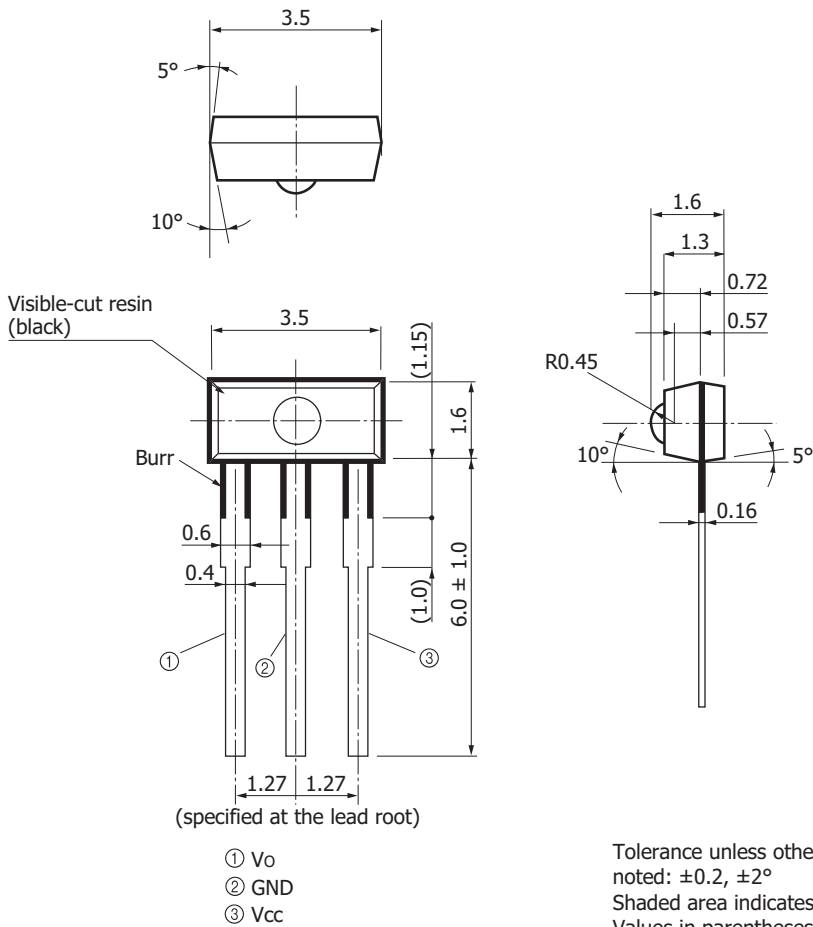
Directivity



Power dissipation vs. ambient temperature



Dimensional outline (unit: mm)



Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

- Disclaimer
- Metal, ceramic, plastic products

Information described in this material is current as of October 2017.

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